

MR2500 SERIES (SILICON)

MEDIUM-CURRENT SILICON RECTIFIERS

... compact, highly efficient silicon rectifiers for medium-current applications requiring:

- High Current Surge – 400 Amperes @ $T_J = 175^\circ\text{C}$
- Peak Performance @ Elevated Temperature – 25 Amperes @ $T_C = 150^\circ\text{C}$
- Low Cost
- Compact, Molded Package – For Optimum Efficiency in a Small Case Configuration

MEDIUM-CURRENT SILICON RECTIFIERS
 60 – 1000 VOLTS
 25 AMPERES
 DIFFUSED JUNCTION



MAXIMUM RATINGS

Characteristic	Symbol	MR 2500	MR 2501	MR 2502	MR 2504	MR 2508	MR 2508	MR 2510	Unit
Peak Repetitive Reverse Voltage	VRRM	50	100	200	400	800	800	1000	Volts
Working Peak Reverse Voltage	VRWM								
DC Blocking Voltage	VR								
Non-Repetitive Peak Reverse Voltage (half wave, single phase, 60 Hz peak)	VRSM	80	120	240	480	720	960	1200	Volts
Average Rectified Forward Current (Single phase, resistive load, 60 Hz, $T_C = 150^\circ\text{C}$)	I_O	← 25 →							Amp
Non-Repetitive Peak Surge Current (surge applied @ rated load conditions, half wave, single phase, 60 Hz)	I_{FSM}	← 400 (for 1 cycle) →							Amp
Operating and Storage Junction Temperature Range	T_J, T_{stg}	← -65 to +175 →							$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (Single Side Cooled)	$R_{\theta JC}$	1.0	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS

Characteristics and Conditions	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage ($I_F = 78.5 \text{ Amp}$, $T_C = 25^\circ\text{C}$)	V_F	1.18	Volts
Maximum Reverse Current (rated dc voltage) $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	I_R	100 500	μA

MECHANICAL CHARACTERISTICS

CASE: Void Free, Transfer Molded.

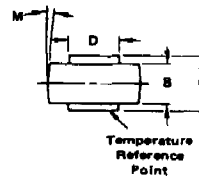
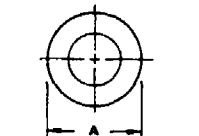
FINISH: All External Surfaces are Corrosion Resistant and the Contact Areas Readily Solderable.

POLARITY: (Indicated by dot on Cathode Side)

MOUNTING POSITIONS: Any

MAXIMUM TEMPERATURE FOR SOLDERING PURPOSES: 250°C

WEIGHT: 1.8 Grams (Approximately)



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	10.03	10.29	0.395	0.405
B	4.19	4.45	0.165	0.175
D	5.54	5.64	0.218	0.222
F	5.94	6.26	0.234	0.248
M	SP NOM		SP NOM	

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